

KSC2073

TV Vertical Deflection Output

- Complement to KSA940
- Collector-Base Voltage : V_{CBO} = 150V



1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Value | Units | |
|------------------|--|------------|-------|--|
| V _{CBO} | Collector-Base Voltage | 150 | V | |
| V _{CEO} | Collector-Emitter Voltage | 150 | V | |
| V _{EBO} | Emitter-Base Voltage | 5 | V | |
| I _C | Collector Current | 1.5 | А | |
| P _C | Collector Dissipation (T _C =25°C) | 25 | W | |
| TJ | Junction Temperature | 150 | °C | |
| T _{STG} | Storage Temperature | - 55 ~ 150 | °C | |

Electrical Characteristics $T_C=25$ °C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|---|------|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_C = 500 \mu A, I_E = 0$ | 150 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | $I_C = 10 \text{mA}, I_B = 0$ | 150 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | $I_E = -500\mu A, I_C = 0$ | 5 | | | V |
| I _{CBO} | Collector Cut-off Current | $V_{CB} = 120V, I_{E} = 0$ | | | 10 | μΑ |
| h _{FE} | DC Current Gain | $V_{CE} = 10V, I_{C} = 0.5A$ | 40 | 75 | 140 | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | $I_C = 500 \text{mA}, I_B = 50 \text{mA}$ | | | 1 | V |
| f _T | Current Gain Bandwidth Product | $V_{CE} = 10V, I_{C} = 0.5A$ | | 4 | | MHz |
| C _{ob} | Output Capacitance | $V_{CB} = 10V, I_E = 0$ f = 1MHz | | 50 | | pF |

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Typical Characteristics

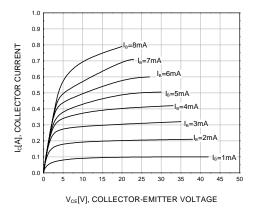


Figure 1. Static Characteristic

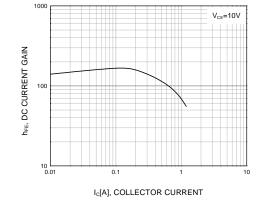


Figure 2. DC current Gain

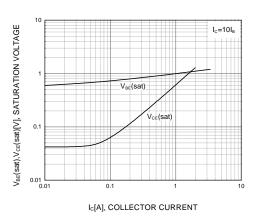


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

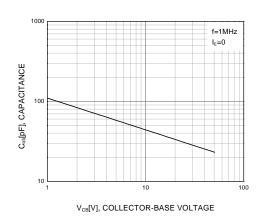


Figure 4. Collector-Emitter On Voltage

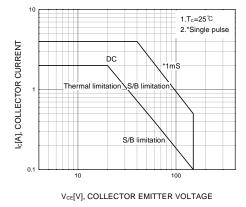


Figure 5. Safe Operating Area

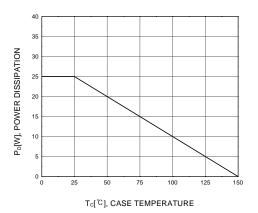
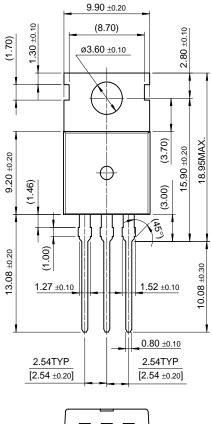


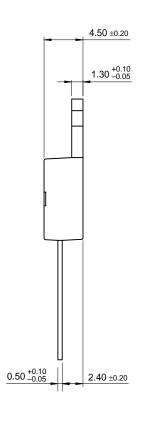
Figure 6. Power Derating

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Package Demensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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